NSN 5961-01-575-6348

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-575-6348 **Inclosure Material:** Ceramic **Overall Length:** Between 0.800 inches and 0.830 inches **Overall Height:** 0.180 mils and 0.203 centimeters **Overall Width:** Between 0.605 inches and 0.631 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 600.0 forward gate to source breakdown voltage **Current Rating Per Characteristic:** 20.00 amperes forward current, average **Special Features:** Zero recovery rectifier **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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